

## N-Channel Enhancement Mode Power MOSFET

### General Features

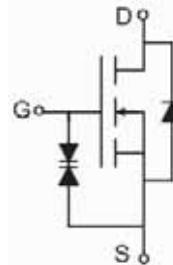
- $V_{DS} = 60V, I_D = 0.3A$
- $R_{DS(ON)} < 3\Omega @ V_{GS}=5V$
- $R_{DS(ON)} < 2\Omega @ V_{GS}=10V$

ESD Rating: HBM 2300V

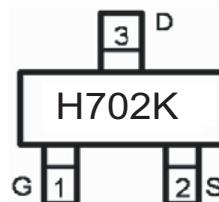
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

### Application

- Direct logic-level interface: TTL/CMOS
- Drivers: relays, solenoids, lamps, hammers, display, memories, transistors, etc.
- Battery operated systems
- Solid-state relays
- P/N suffix V means AEC-Q101 qualified, e.g.:2N7002KV
- Halogen-free



Schematic diagram



Marking and pin assignment



SOT-23 top view

### Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
H702K	2N7002K	SOT-23	Ø180mm	8 mm	3000 units

### Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current ( $T_J = 150^\circ C$ )	$I_D$	0.3	A
		0.19	
Drain Current-Pulsed <sup>(Note 1)</sup>	$I_{DM}$	0.8	A
Maximum Power Dissipation	$P_D$	0.35	W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	°C

### Thermal Characteristic

Thermal Resistance, Junction-to-Ambient <sup>(Note 2)</sup>	$R_{\theta JA}$	350	°C/W
---	-----------------	-----	------

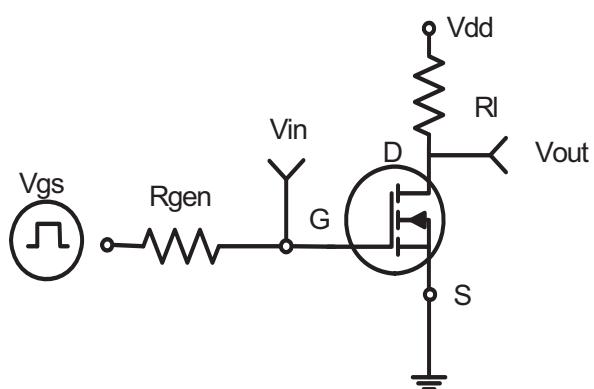
## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	60	68	-	V
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=60\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	$\mu\text{A}$
Gate-Body Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 10\text{V}, V_{\text{DS}}=0\text{V}$	-	$\pm 100$	$\pm 500$	nA
		$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$	-	$\pm 4$	$\pm 10$	$\mu\text{A}$
<b>On Characteristics</b> <sup>(Note 3)</sup>						
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	1	1.7	1.9	V
Drain-Source On-State Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=5\text{V}, I_{\text{D}}=0.4\text{A}$	-	1.3	3	$\Omega$
		$V_{\text{GS}}=10\text{V}, I_{\text{D}}=0.5\text{A}$	-	1	2	$\Omega$
Forward Transconductance	$g_{\text{FS}}$	$V_{\text{DS}}=10\text{V}, I_{\text{D}}=0.2\text{A}$	0.1	-	-	S
<b>Dynamic Characteristics</b> <sup>(Note 4)</sup>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=25\text{V}, V_{\text{GS}}=0\text{V}, F=1.0\text{MHz}$	-	21	50	PF
Output Capacitance	$C_{\text{oss}}$		-	11	25	PF
Reverse Transfer Capacitance	$C_{\text{rss}}$		-	4.2	5	PF
<b>Switching Characteristics</b> <sup>(Note 4)</sup>						
Turn-on Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=30\text{V}, I_{\text{D}}=0.2\text{A}$ $V_{\text{GS}}=10\text{V}, R_{\text{GEN}}=10\Omega$	-	10	-	nS
Turn-on Rise Time	$t_r$		-	50	-	nS
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$		-	17	-	nS
Turn-Off Fall Time	$t_f$		-	10	-	nS
Total Gate Charge	$Q_g$	$V_{\text{DS}}=10\text{V}, I_{\text{D}}=0.3\text{A}, V_{\text{GS}}=4.5\text{V}$	-	1.7	3	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <sup>(Note 3)</sup>	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V}, I_{\text{s}}=0.2\text{A}$	-	-	1.3	V
Diode Forward Current <sup>(Note 2)</sup>	$I_{\text{s}}$		-	-	0.2	A

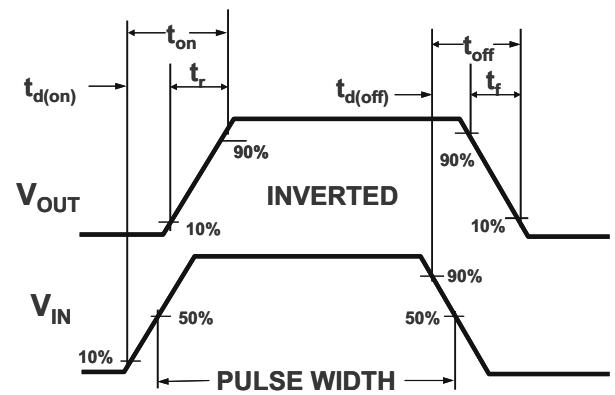
### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production

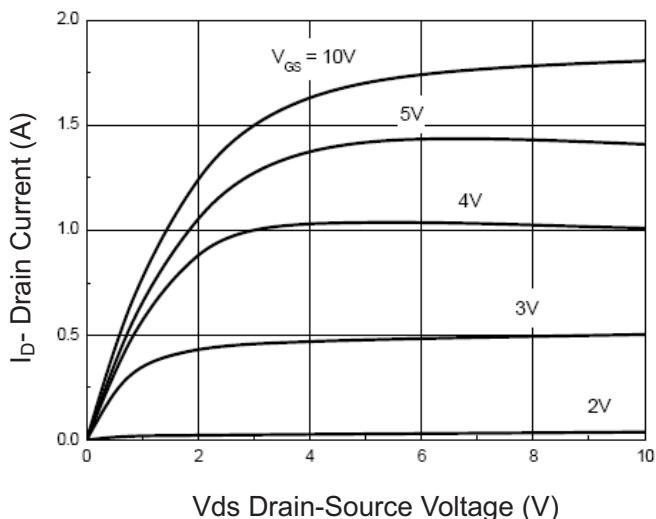
## RATING AND CHARACTERISTICS CURVES (2N7002KV)



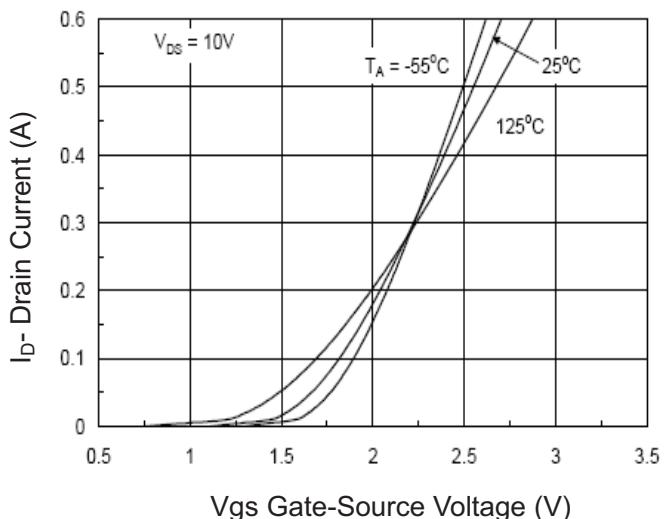
**Figure 1:Switching Test Circuit**



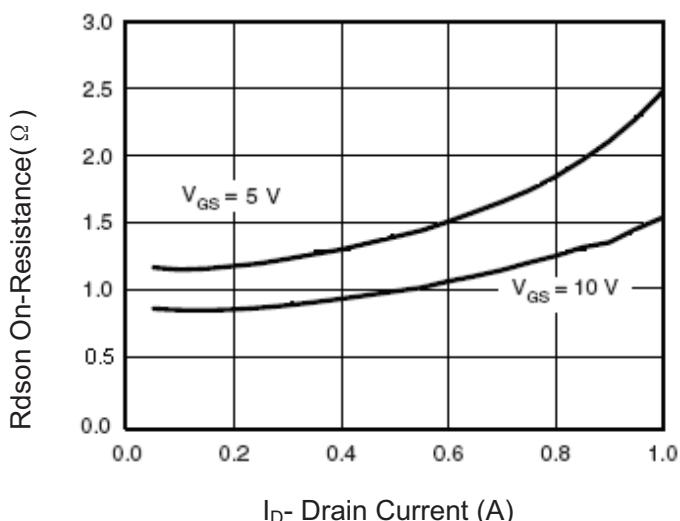
**Figure 2:Switching Waveforms**



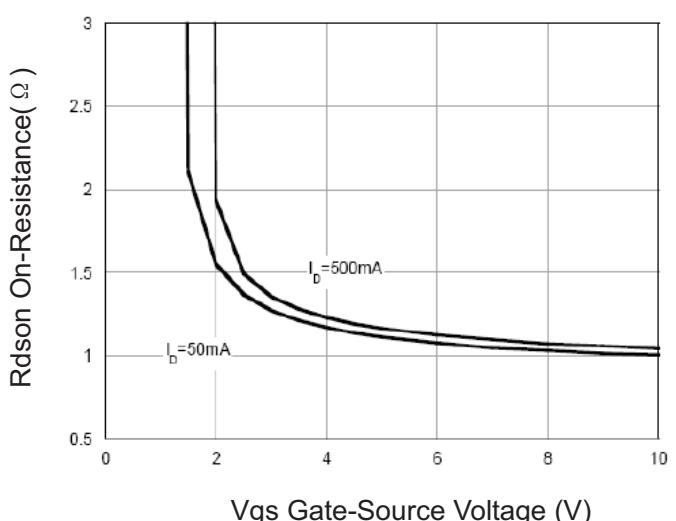
**Figure 3 Output Characteristics**



**Figure 4 Transfer Characteristics**

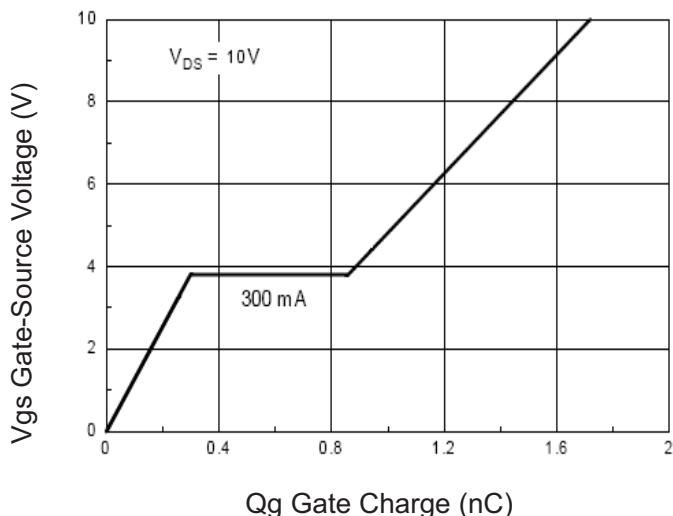


**Figure 5 Drain-Source On-Resistance**

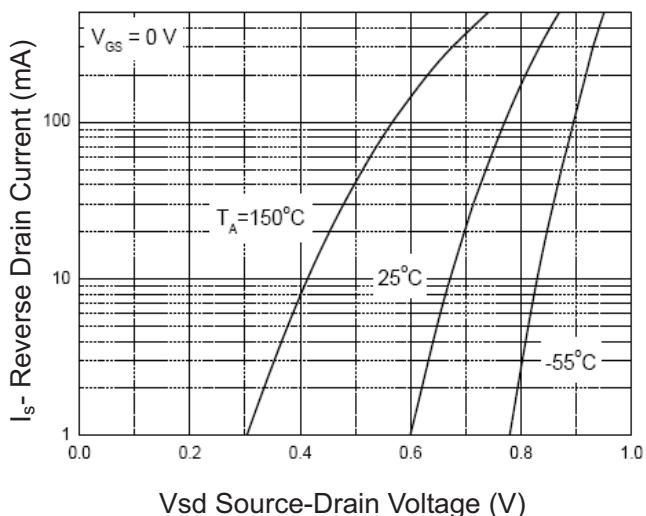


**Figure 6 Rdson vs Vgs**

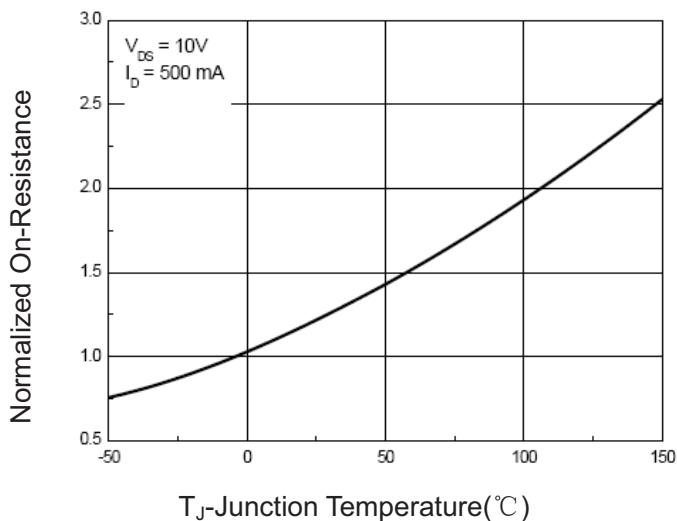
## RATING AND CHARACTERISTICS CURVES (2N7002KV)



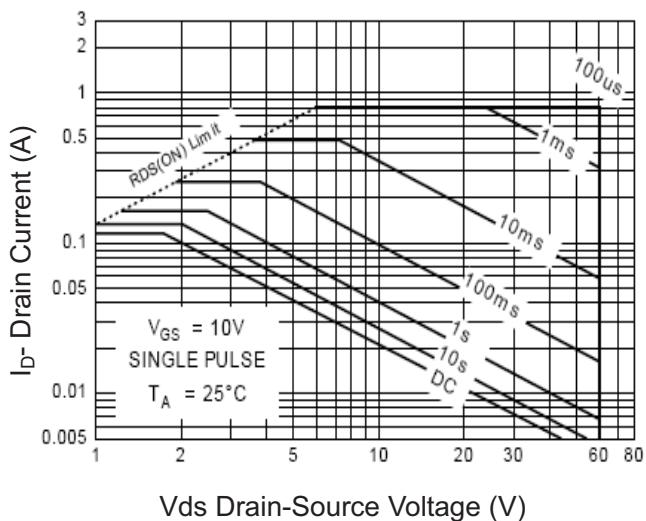
**Figure 7 Gate Charge**



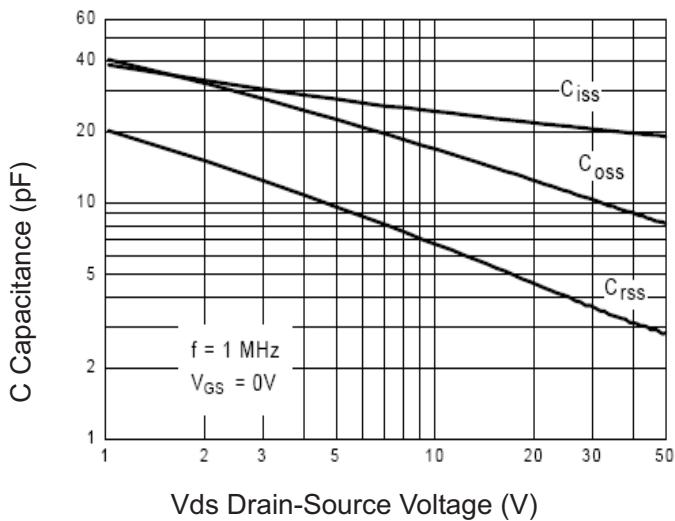
**Figure 8 Source-DrainDiode Forward**



**Figure 9 Drain-Source On-Resistance**

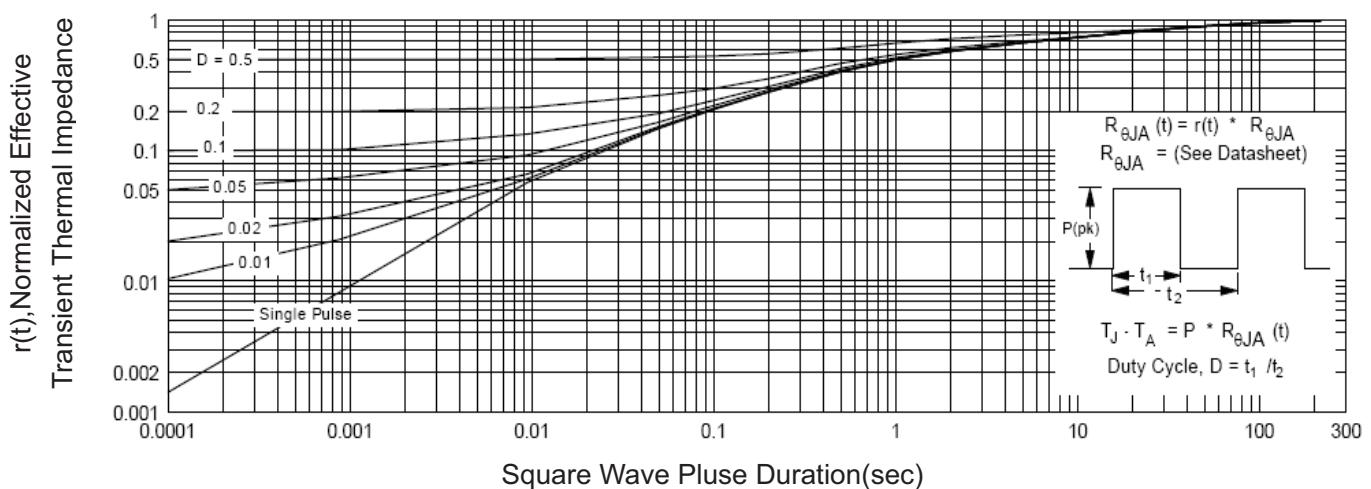


**Figure 10 Safe Operation Area**



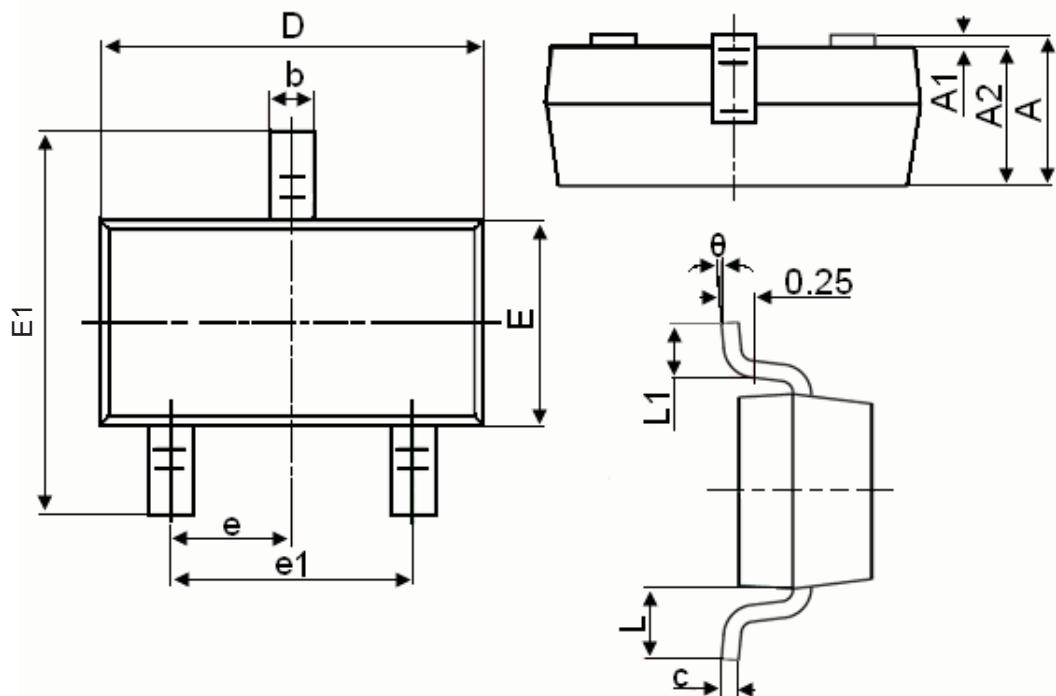
**Figure 11 Capacitance vs Vds**

## RATING AND CHARACTERISTICS CURVES (2N7002KV)



**Figure 12 Normalized Maximum Transient Thermal Impedance**

## SOT-23 Package Information



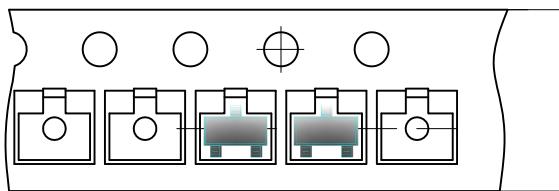
Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

### Notes

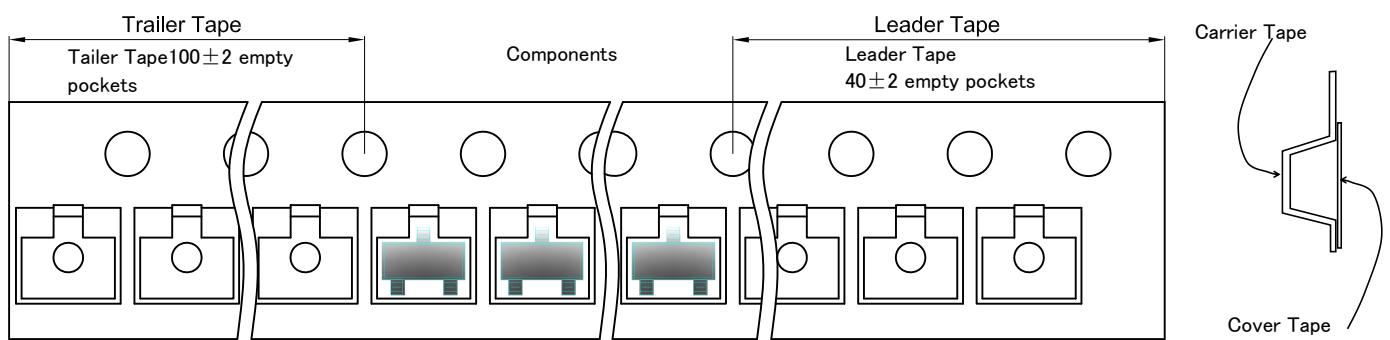
1. All dimensions are in millimeters.
2. Tolerance  $\pm 0.10\text{mm}$  (4 mil) unless otherwise specified
3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
4. Dimension L is measured in gauge plane.
5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

## Packing Configuration

Conductive Embossed Carrier Tape



## Tape Leader and Trailer Configuration



Package	Tape&Reel (pcs/reel)	Tape&Reel (pcs/inner box)	Tape&Reel (pcs/cartoon)
SOT-23	3,000	30,000	120,000

## **DISCLAIMER NOTICE**

Rectron Inc reserves the right to make changes without notice to any product specification herein, to make corrections, modifications, enhancements or other changes. Rectron Inc or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies. Data sheet specifications and its information contained are intended to provide a product description only. "Typical" parameters which may be included on RECTRON data sheets and/ or specifications can and do vary in different applications and actual performance may vary over time. Rectron Inc does not assume any liability arising out of the application or use of any product or circuit.

Rectron products are not designed, intended or authorized for use in medical, life-saving implant or other applications intended for life-sustaining or other related applications where a failure or malfunction of component or circuitry may directly or indirectly cause injury or threaten a life without expressed written approval of Rectron Inc. Customers using or selling Rectron components for use in such applications do so at their own risk and shall agree to fully indemnify Rectron Inc and its subsidiaries harmless against all claims, damages and expenditures.

# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

***Click to view similar products for Rectron manufacturer:***

Other Similar products are found below :

[061172EB](#) [10A05](#) [10A10-T](#) [10A2-B](#) [10A6-T](#) [1.5KE300CA-T](#) [1A1-B](#) [1D4](#) [1H1-B](#) [1N4001-B](#) [1N4001G](#) [1N4002-B](#) [1N4003-B](#) [1N4003-T](#)  
[1N4004-B](#) [1N4004G-B](#) [1N4004-T](#) [1N4148](#) [1N4148-B](#) [1N4148-T](#) [1N4151-B](#) [1N4454-T](#) [1N4758A-B](#) [1N4947-B](#) [1N5226B-B](#) [1N5231B-B](#)  
[1N5232B-B](#) [1N5236B-B](#) [1N5239B-B](#) [1N5250B-B](#) [1N5258B-B](#) [1N5359B-T](#) [1N5402-B](#) [1N5404-B](#) [1N5406-T](#) [1N5408](#) [1N5408G-B](#)  
[1N5817-T](#) [1N5818-B](#) [1N5818-T](#) [1N5822-T](#) [1N914B-B](#) [1S40-T](#) [1SMB5934B-W](#) [1SMB5936B-W](#) [2N3904](#) [2N4401](#) [2N4401-T](#) [2N4403](#)  
[2N5401-F](#)